

AS5045B

12-Bit Programmable Magnetic Position Sensor

1 General Description

The AS5045B is a contact less magnetic position sensor for accurate angular measurement over a full turn of 360 degrees.

It is a system-on-chip, combining integrated Hall elements, analog front end and digital signal processing in a single device.

To measure the angle, only a simple two-pole magnet, rotating over the center of the chip, is required. The magnet can be placed above or below the IC.

The absolute angle measurement provides instant indication of the magnet's angular position with a resolution of $0.0879^\circ = 4096$ positions per revolution. This digital data is available as a serial bit stream and as a PWM signal.

An internal voltage regulator allows the AS5045B to operate at either 3.3V or 5V supplies.

- Two digital 12-bit absolute outputs:
 - Serial interface
 - Pulse width modulated (PWM) output
- Quadrature A/B/I output 12-bit
- User programmable zero position
- Failure detection mode for magnet placement, monitoring, and loss of power supply
- Red-Yellow-Green indicators display placement of magnet in Z-axis
- Serial read-out of multiple interconnected AS5045B devices using Daisy Chain mode
- Tolerant to magnet misalignment and gap variations
- Wide temperature range: - 40°C to +125°C
- Small Pb-free package: SSOP 16 (5.3mm x 6.2mm)

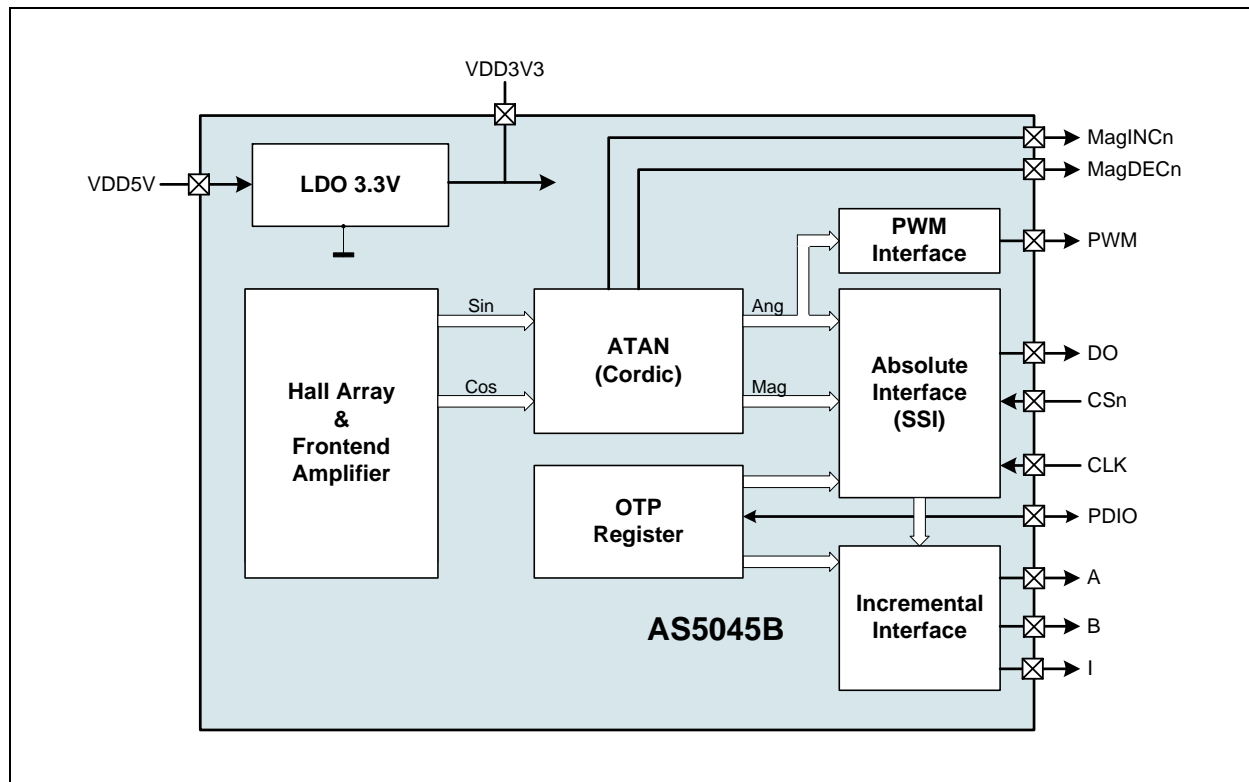
2 Key Features

- Contact less high resolution rotary position sensor over a full turn of 360 degrees

3 Applications

The device is ideal for industrial applications like automatic or elevator doors, robotics, motor control and optical encoder replacement.

Figure 1. Blockdiagram Rotary Position Sensor IC





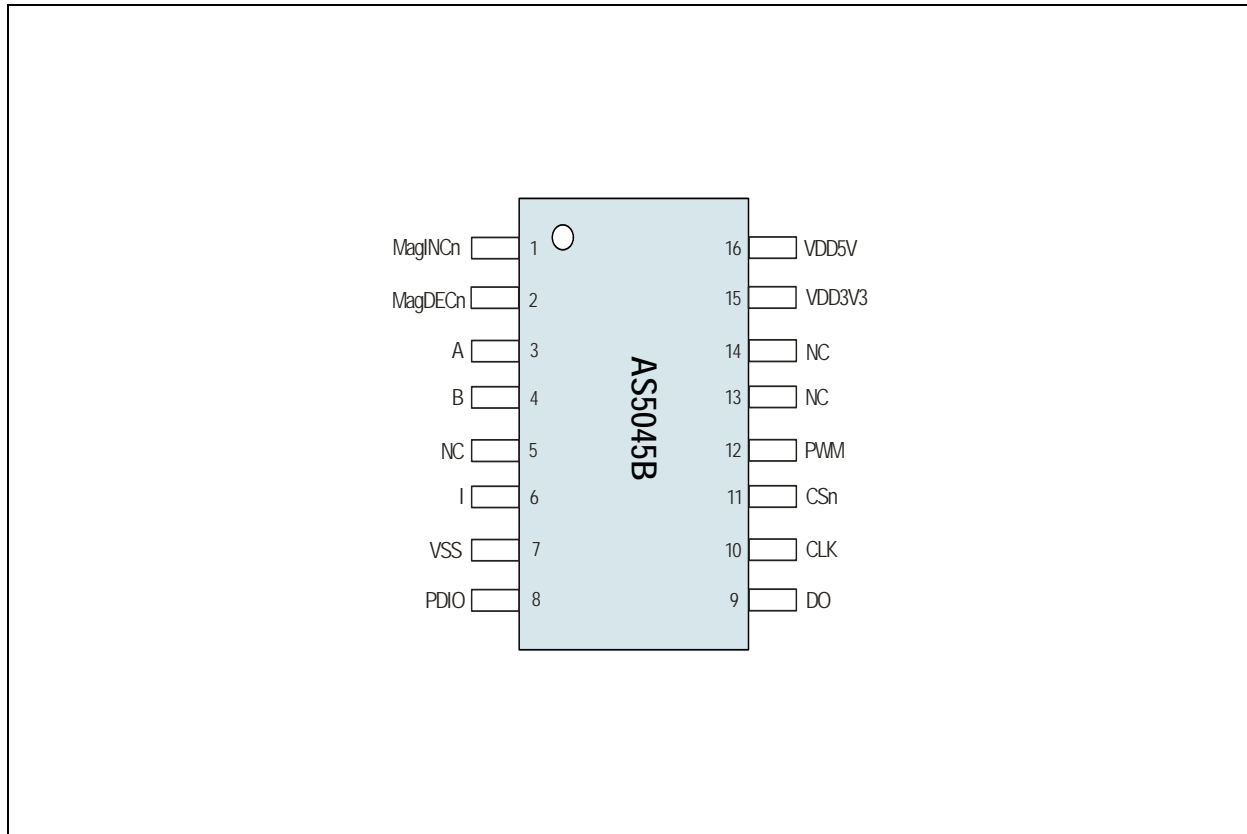
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4 Pin Assignments

Figure 2. Pin Assignments (Top View)



4.1 Pin Descriptions

The following SSOP16 shows the description of each pin of the standard SSOP16 package (Shrink Small Outline Package, 16 leads, body size: 5.3mm x 6.2mm; (see Figure 2).

Table 1. Pin Descriptions

Pin Name	Pin Number	Pin Type	Description
MagINCn	1	Digital output open drain	Magnet Field Magnitude Increase. Active low. Indicates a distance reduction between the magnet and the device surface. (see Table 8)
MagDECn	2		Magnet Field Magnitude Decrease. Active low. Indicates a distance increase between the device and the magnet. (see Table 8)
A	3	Digital output	Quadrature output A (1024 Pulses)
B	4		Quadrature output B (1024 Pulses)
NC	5	-	Must be left unconnected
I	6	Digital output	Index signal for the quadrature output.
Vss	7	Supply pin	Negative Supply Voltage (GND)
PDIO	8	Digital input pull-down	OTP Programming Input and Data Input for Daisy Chain mode. Pin has an internal pull-down resistor (74kΩ). Connect this pin to VSS if programming is not required.
DO	9	Digital output/ tri-state	Data Output of Synchronous Serial Interface
CLK	10	Digital input, Schmitt-Trigger input	Clock Input of Synchronous Serial Interface; Schmitt-Trigger input



Table 1. Pin Descriptions

Pin Name	Pin Number	Pin Type	Description
CSn	11	Digital input pull-down, Schmitt-Trigger input	Chip Select. Active low. Schmitt-Trigger input, internal pull-up resistor (50k Ω)
PWM	12	Digital output	Pulse Width Modulation
NC	13	-	Must be left unconnected
NC	14	-	Must be left unconnected
VDD3V3	15	Supply pin	3V-Regulator Output, internally regulated from VDD5V. Connect to VDD5V for 3V supply voltage. Do not load externally.
VDD5V	16	Supply pin	Positive Supply Voltage, 3.0V to 5.5V

Pin 1 and 2 are the magnetic field change indicators, MagINCn and MagDECn (magnetic field strength increase or decrease through variation of the distance between the magnet and the device). These outputs can be used to detect the valid magnetic field range. Furthermore those indicators can also be used for contact-less push-button functionality.

Pin 3 and 4 are used for incremental angle information in 12-bit quadrature signal format.

Pin 6 Index output used for incremental angle information. (Zero position reference).

Pins 7, 15, and 16 are supply pins, pins 5, 13, and 14 are for internal use and must not be connected.

Pin 8 (PDIO) is used to program the zero-position into the OTP(see [page 17](#)). This pin is also used as digital input to shift serial data through the device in Daisy Chain configuration, (see [page 13](#)).

Pin 11 Chip Select (CSn; active low) selects a device within a network of AS5045Bs and initiates serial data transfer. A logic high at CSn puts the data output pin (DO) to tri-state and terminates serial data transfer. This pin is also used for alignment mode (see [Alignment Mode on page 21](#)) and programming mode (see [Programming the AS5045B on page 17](#)).

Pin 12 allows a single wire output of the 12-bit absolute position value. The value is encoded into a pulse width modulated signal with 1 μ s pulse width per step (1 μ s to 4096 μ s over a full turn). By using an external low pass filter, the digital PWM signal is converted into an analog voltage, e.g. for making a direct replacement of potentiometers possible.



5 Absolute Maximum Ratings

Stresses beyond those listed in [Table 2](#) may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in [Section 6 Electrical Characteristics on page 6](#) is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 2. Absolute Maximum Ratings

Parameter	Min	Max	Units	Comments
Electrical Parameters				
DC supply voltage at pin VDD5V	-0.3	7	V	
DC supply voltage at pin VDD3V3		5	V	
Input pin voltage	-0.3	VDD5V +0.3	V	Except VDD3V3
Input current (latchup immunity)	-100	100	mA	Norm: EIA/JESD78 Class II Level A
Electrostatic Discharge				
Electrostatic discharge		± 2	kV	Norm: JESD22-A114E
Temperature Ranges and Storage Conditions				
Storage temperature	-55	150	°C	Min -67°F; Max +302°F
Package Body temperature		260	°C	The reflow peak soldering temperature (body temperature) specified is in accordance with <i>IPC/JEDEC J-STD-020 "Moisture/Reflow Sensitivity Classification for Non-Hermetic Solid State Surface Mount Devices"</i> . The lead finish for Pb-free leaded packages is matte tin (100% Sn).
Humidity non-condensing	5	85	%	
Moisture Sensitive Level (MSL)		3		Represents a maximum floor time of 168h



6 Electrical Characteristics

T_{AMB} = -40 to +125°C, V_{DD5V} = 3.0-3.6V (3V operation) V_{DD5V} = 4.5-5.5V (5V operation) unless otherwise noted. Also valid for version I.

Table 3. Electrical Characteristics

Symbol	Parameter	Condition	Min	Typ	Max	Unit
Operating Conditions						
T _{AMB}	Ambient temperature	Version I	-40		+125	°C
I _{supp}	Supply current			16	21	mA
V _{DD5V}	Supply voltage at pin V _{DD5V}	5V Operation	4.5	5.0	5.5	V
V _{DD3V3}	Voltage regulator output voltage at pin V _{DD3V3}		3.0	3.3	3.6	
V _{DD5V}	Supply voltage at pin V _{DD5V}	3.3V Operation (pin V _{DD5V} and V _{DD3V3} connected)	3.0	3.3	3.6	V
V _{DD3V3}	Supply voltage at pin V _{DD3V3}		3.0	3.3	3.6	
V _{ON}	Power-on reset thresholds On voltage; 300mV typ. hysteresis	DC supply voltage 3.3V (V _{DD3V3})	1,37	2.2	2.9	V
V _{off}	Power-on reset thresholds Off voltage; 300mV typ. hysteresis		1.08	1.9	2.6	
Programming Conditions						
V _{PROG}	Programming voltage	Voltage applied during programming	3.3		3.6	V
V _{ProgOff}	Programming voltage off level	Line must be discharged to this level	0		1	V
I _{PROG}	Programming current	Current during programming			100	mA
R _{programmed}	Programmed fuse resistance (log 1)	10µA max. current @ 100mV	100k		∞	Ω
R _{unprogrammed}	Unprogrammed fuse resistance (log 0)	2mA max. current @ 100mV	50		100	Ω
DC Characteristics CMOS Schmitt-Trigger Inputs: CLK, CSn (CSn = Internal Pull-up)						
V _{IH}	High level input voltage	Normal operation	0.7 * V _{DD5V}			V
V _{IL}	Low level input voltage				0.3 * V _{DD5V}	V
V _{Ion} - V _{Ioff}	Schmitt Trigger hysteresis		1			V
I _{LEAK}	Input leakage current	CLK only	-1		1	µA
I _{IL}	Pull-up low level input current	CSn only, V _{DD5V} : 5.0V	-30		-100	
DC Characteristics CMOS / Program Input: PDIO						
V _{IH}	High level input voltage		0.7 * V _{DD5V}		V _{DD5V}	V
V _{PROG} ¹	High level input voltage	During programming	3.3		3.6	V
V _{IL}	Low level input voltage				0.3 * V _{DD5V}	V
I _{IL}	High level input current	V _{DD5V} : 5.5V	30		100	µA
DC Characteristics CMOS Output Open Drain: MagINCn, MagDECn						
I _{OZ}	Open drain leakage current				1	µA
V _{OL}	Low level output voltage				V _{SS} + 0.4	V



Table 3. Electrical Characteristics

Symbol	Parameter	Condition	Min	Typ	Max	Unit
I _O	Output current	V _{DD} 5V: 4.5V			4	mA
		V _{DD} 5V: 3V			2	
DC Characteristics CMOS Output: PWM						
V _{OH}	High level output voltage		V _{DD} 5V–0.5			V
V _{OL}	Low level output voltage				V _{SS} +0.4	V
I _O	Output current	V _{DD} 5V: 4.5V			4	mA
		V _{DD} 5V: 3V			2	
DC Characteristics CMOS Output: A, B, Index						
V _{OH}	High level output voltage		V _{DD} 5V–0.5			V
V _{OL}	Low level output voltage				V _{SS} +0.4	V
I _O	Output current	V _{DD} 5V: 4.5V			4	mA
		V _{DD} 5V: 3V			2	
DC Characteristics Tri-state CMOS Output: DO						
V _{OH}	High level output voltage		V _{DD} 5V–0.5			V
V _{OL}	Low level output voltage				V _{SS} +0.4	V
I _O	Output current	V _{DD} 5V: 4.5V			4	mA
		V _{DD} 5V: 3V			2	
I _{OZ}	Tri-state leakage current				1	μA

1. Either with 3.3V or 5V supply.

6.1 Magnetic Input Specification

$T_{AMB} = -40$ to $+125^\circ C$, $V_{DD5V} = 3.0$ to $3.6V$ (3V operation) $V_{DD5V} = 4.5$ to $5.5V$ (5V operation) unless otherwise noted. Also valid for version I.

Two-pole cylindrical diametrically magnetized source:

Table 4. Magnetic Input Specification

Symbol	Parameter	Condition	Min	Typ	Max	Unit
d_{mag}	Diameter	Recommended magnet: $\varnothing 6mm \times 2.5mm$ for cylindrical magnets	4	6		mm
t_{mag}	Thickness		2.5			mm
B_{pk}	Magnetic input field amplitude	Required vertical component of the magnetic field strength on the die's surface, measured along a concentric circle with a radius of 1.1mm	45		75	mT
B_{off}	Magnetic offset	Constant magnetic stray field			± 10	mT
f_{mag_abs}	Input frequency (rotational speed of magnet)	153 rpm @ 4096 positions/rev			2.54	Hz
Disp	Displacement radius	Max. offset between defined device center and magnet axis (see Figure 17)			0.25	mm



Table 4. Magnetic Input Specification

Symbol	Parameter	Condition	Min	Typ	Max	Unit
Ecc	Eccentricity	Eccentricity of magnet center to rotational axis			100	μm
	Recommended magnet material and temperature drift	NdFeB (Neodymium Iron Boron)		-0.12		%K
		SmCo (Samarium Cobalt)		-0.035		

6.2 System Specifications

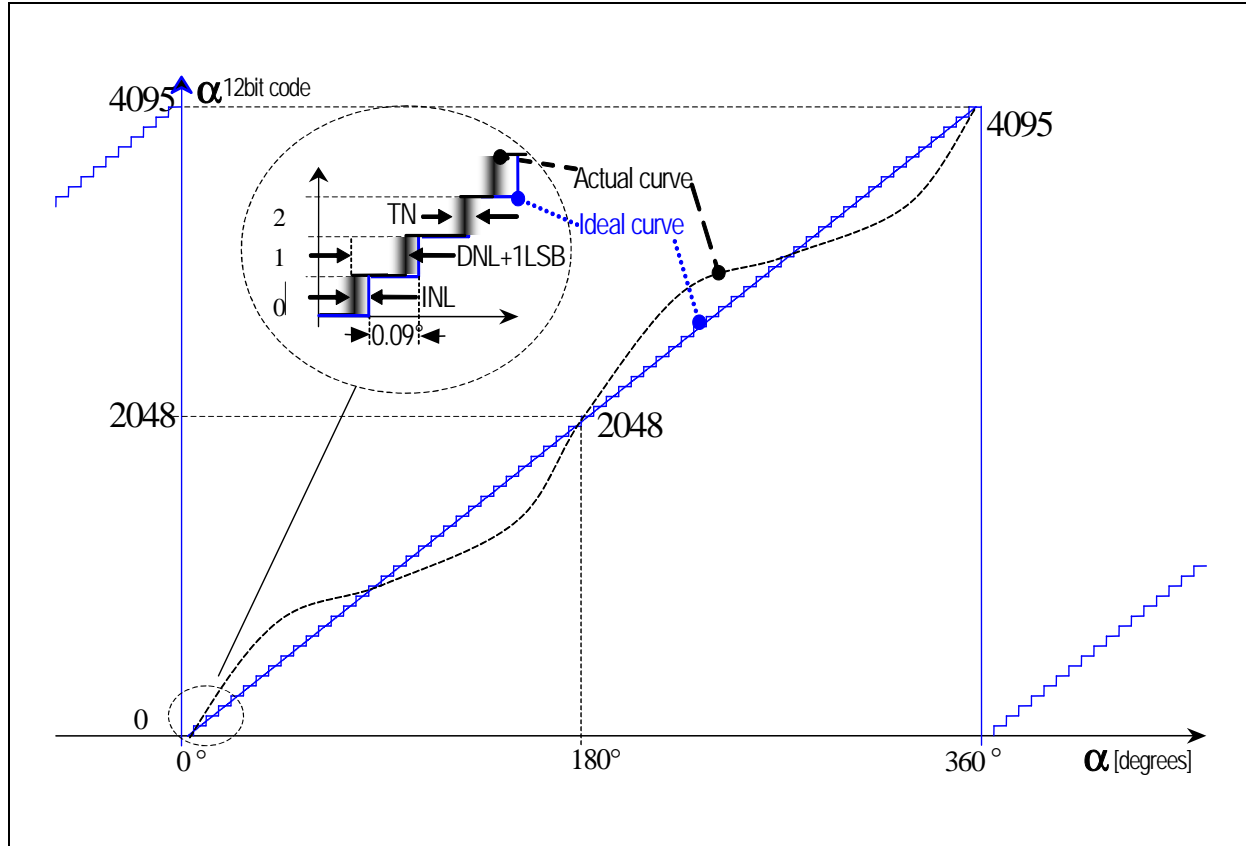
T_{AMB} = -40 to +125°C, V_{DD5V} = 3.0 to 3.6V (3V operation) V_{DD5V} = 4.5 to 5.5V (5V operation) unless otherwise noted. Also valid for version I.

Table 5. Input Specification

Symbol	Parameter	Condition	Min	Typ	Max	Unit
RES	Resolution	0.088 deg			12	bit
INL _{opt}	Integral non-linearity (optimum)	Maximum error with respect to the best line fit. Centered magnet without calibration, T _{AMB} = 25 °C.			± 0.5	deg
INL _{temp}	Integral non-linearity (optimum)	Maximum error with respect to the best line fit. Centered magnet without calibration, T _{AMB} = -40 to +125°C			± 0.9	deg
INL	Integral non-linearity	Best line fit = (Err _{max} - Err _{min}) / 2 Over displacement tolerance with 6mm diameter magnet, without calibration, T _{AMB} = -40 to +125°C			± 1.4	deg
DNL	Differential non-linearity	12-bit, no missing codes			± 0.044	deg
TN	Transition noise	1 sigma			0.06	Deg RMS
t _{PwrUp}	Power-up time	Until status bit OCF = 1			20	ms
t _{delay}	System propagation delay absolute output : delay of ADC, DSP and absolute interface				96	μs
t _{delayINC}	System propagation delay incremental output				192	μs
f _S	Internal sampling rate for absolute output		9.38	10.42	11.46	kHz
CLK/SEL	Read-out frequency	Max. clock frequency to read out serial data			1	MHz



Figure 3. Integral and Differential Non-Linearity Example



Integral Non-Linearity (INL) is the maximum deviation between actual position and indicated position.

Differential Non-Linearity (DNL) is the maximum deviation of the step length from one position to the next.

Transition Noise (TN) is the repeatability of an indicated position.



7 Timing Characteristics

T_{AMB} = -40 to +125 °C, V_{DD5V} = 3.0 to 3.6V (3V operation) V_{DD5V} = 4.5 to 5.5V (5V operation), unless otherwise noted. Also valid for version I.

Table 6. Timing Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Units
Synchronous Serial Interface (SSI)						
t _{DOactive}	Data output activated (logic high)	Time between falling edge of CSn and data output activated			100	ns
t _{CLKFE}	First data shifted to output register	Time between falling edge of CSn and first falling edge of CLK	500			ns
T _{CLK/2}	Start of data output	Rising edge of CLK shifts out one bit at a time	500			ns
t _{DOvalid}	Data output valid	Time between rising edge of CLK and data output valid			413	ns
t _{DOtristate}	Data output tri-state	After the last bit DO changes back to "tri-state"			100	ns
t _{CSn}	Pulse width of CSn	CSn =high; To initiate read-out of next angular position	500			ns
f _{CLK}	Read-out frequency	Clock frequency to read out serial data	>0		1	MHz
Pulse Width Modulation Output						
f _{PWM}	PWM frequency	Signal period = 4098μs ±10% at T _{AMB} = -40 to +125°C	220	244	268	Hz
PW _{MIN}	Minimum pulse width	Position 0d; angle 0 degree	0.90	1	1.10	μs
PW _{MAX}	Maximum pulse width	Position 4098d; angle 359.91 degrees	3686	4096	4506	μs
Programming Conditions						
t _{PROG}	Programming time per bit	Time to prog. a single fuse bit	10		20	μs
t _{CHARGE}	Refresh time per bit	Time to charge the cap after t _{PROG}	1			μs
f _{LOAD}	LOAD frequency	Data can be loaded at n x 2μs			500	kHz
f _{READ}	READ frequency	Read the data from the latch			2.5	MHz
f _{WRITE}	WRITE frequency	Write the data to the latch			2.5	MHz



8 Detailed Description

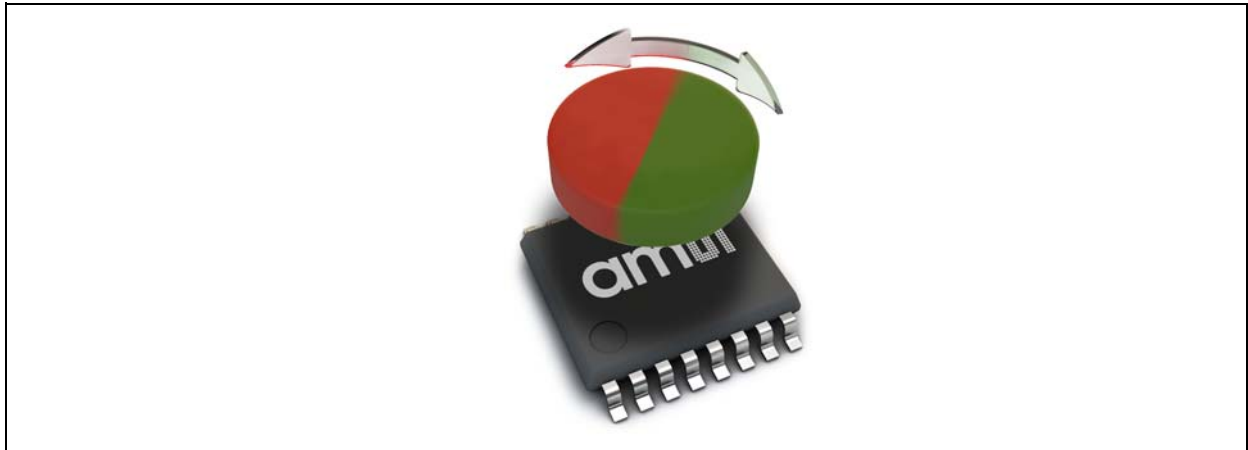
The AS5045B is manufactured in a CMOS standard process and uses a spinning current Hall technology for sensing the magnetic field distribution across the surface of the chip. The integrated Hall elements are placed around the center of the device and deliver a voltage representation of the magnetic field at the surface of the IC.

Through Sigma-Delta Analog / Digital Conversion and Digital Signal-Processing (DSP) algorithms, the AS5045B provides accurate high-resolution absolute angular position information. For this purpose a Coordinate Rotation Digital Computer (CORDIC) calculates the angle and the magnitude of the Hall array signals.

The DSP is also used to provide digital information at the outputs MagINCn and MagDECn that indicate movements of the used magnet towards or away from the device's surface. A small low cost diametrically magnetized (two-pole) standard magnet provides the angular position information (see Figure 16).

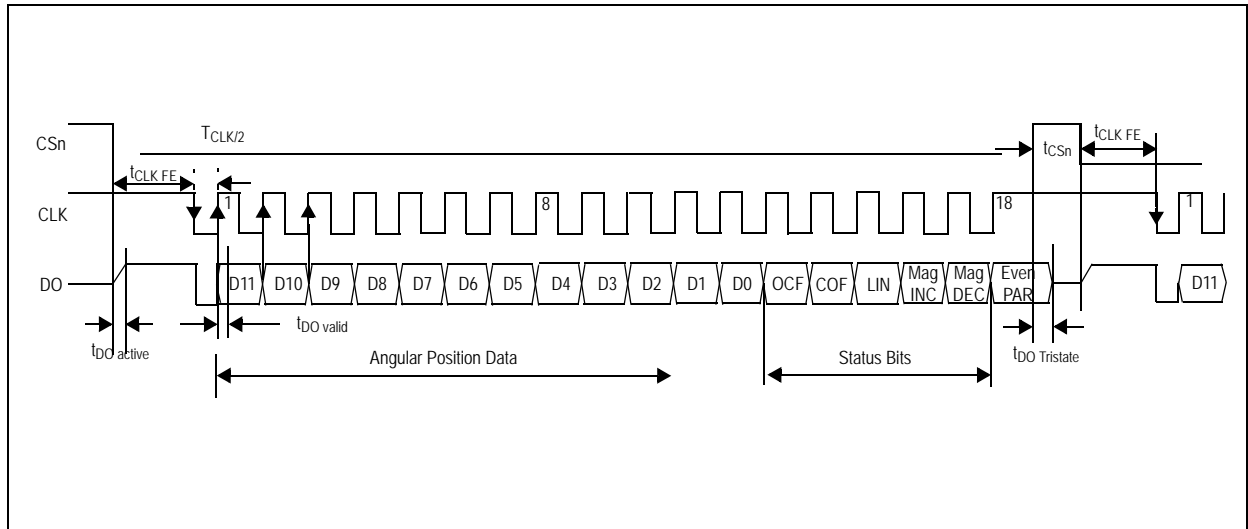
The AS5045B senses the orientation of the magnetic field and calculates a 12-bit binary code. This code can be accessed via a Synchronous Serial Interface (SSI). In addition, an absolute angular representation is given by a Pulse Width Modulated signal at pin 12 (PWM). This PWM signal output also allows the generation of a direct proportional analog voltage, by using an external Low-Pass-Filter. The AS5045B is tolerant to magnet misalignment and magnetic stray fields due to differential measurement technique and Hall sensor conditioning circuitry.

Figure 4. Typical Arrangement of AS5045B and Magnet



8.1 Synchronous Serial Interface (SSI)

Figure 5. Synchronous Serial Interface with Absolute Angular Position Data





If CSn changes to logic low, Data Out (DO) will change from high impedance (tri-state) to logic high and the read-out will be initiated.

- After a minimum time $t_{CLK\ FE}$, data is latched into the output shift register with the first falling edge of CLK.
- Each subsequent rising CLK edge shifts out one bit of data.
- The serial word contains 18 bits, the first 12 bits are the angular information D[11:0], the subsequent 6 bits contain system information, about the validity of data such as OCF, COF, LIN, Parity and Magnetic Field status (increase/decrease).
- A subsequent measurement is initiated by a "high" pulse at CSn with a minimum duration of t_{CSn} .

Data Content

D11:D0 absolute angular position data (MSB is clocked out first)

OCF (Offset Compensation Finished), logic high indicates the finished Offset Compensation Algorithm

COF (Cordic Overflow), logic high indicates an out of range error in the CORDIC part. When this bit is set, the data at D11:D0 is invalid. The absolute output maintains the last valid angular value.

This alarm can be resolved by bringing the magnet within the X-Y-Z tolerance limits.

LIN (Linearity Alarm), logic high indicates that the input field generates a critical output linearity.

When this bit is set, the data at D11:D0 can still be used, but can contain invalid data. This warning can be resolved by bringing the magnet within the X-Y-Z tolerance limits.

Even Parity bit for transmission error detection of bits 1...17 (D11...D0, OCF, COF, LIN, MagINC, MagDEC)

Placing the magnet above the chip, angular values increase in clockwise direction by default.

Data D11:D0 is valid, when the status bits have the following configurations:

Table 7. Status Bit Outputs

OCF	COF	LIN	Mag INC	Mag DEC	Parity
1	0	0	0	0	Even checksum of bits 1:15
			0	1	
			1	0	
			1	1	

Note: MagInc=MagDec=1 is only recommended in YELLOW mode (see Table 8)

Z-axis Range Indication (Push Button Feature, Red/Yellow/Green Indicator). The AS5045B provides several options of detecting movement and distance of the magnet in the Z-direction. Signal indicators MagINCn and MagDECn are available both as hardware pins (pins #1 and 2) and as status bits in the serial data stream (see Figure 5).

In the default state, the status bits MagINC, MagDec and pins MagINCn, MagDECn have the following function:

Table 8. Magnetic Field Strength Red-Yellow-Green Indicator

Status Bits			Hardware Pins		OTP: Mag CompEn = 1 (Red-Yellow-Green)
Mac INC	Mag DEC	LIN	Mac INCn	Mag DECn	Description
0	0	0	Off	Off	No distance change Magnetic input field OK (GREEN range, ~45...75mT)
1	1	0	On	Off	YELLOW range: magnetic field is ~ 25...45mT or ~75...135mT. The AS5045B can still be operated in this range, but with slightly reduced accuracy.
1	1	1	On	On	RED range: magnetic field is ~<25mT or >~135mT. It is still possible to operate the AS5045B in the red range, but not recommended.
All other combinations			n/a	n/a	Not available

Note: Pin 1 (MagINCn) and pin 2 (MagDECn) are active low via open drain output and require an external pull-up resistor. If the magnetic field is in range, both outputs are turned off.



The two pins can also be combined with a single pull-up resistor. In this case, the signal is high when the magnetic field is in range. It is low in all other cases (see Table 8).

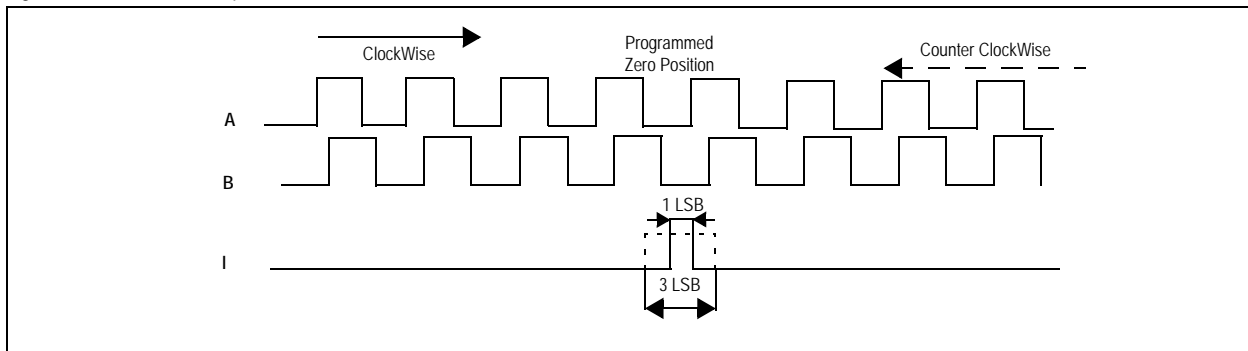
8.2 Incremental Mode

The AS5045B has an internal interpolator block. This function is used if the input magnetic field is too fast and a code position is missing. In this case an interpolation is done.

Incremental Power-up Lock Option. After power-up, the incremental outputs can optionally be locked or unlocked, depending on the status of the CSn pin:

- CSn = low at power-up: CSn has an internal pull-up resistor and must be externally pulled low ($R_{ext} \leq 5k\Omega$). If CSn is low at power-up, the incremental outputs (A, B, Index) will be high until the internal offset compensation is finished. This unique state (A=B=Index = high) can be used as an indicator for the external controller to shorten the waiting time at power-up. Instead of waiting for the specified maximum power up-time (0), the controller can start requesting data from the AS5045B as soon as the state (A=B=Index = high) is cleared.
- CSn = high or open at power-up: In this mode, the incremental outputs (A, B, Index) will remain at logic high state, until CSn goes low or a low pulse is applied at CSn. This mode allows intentional disabling of the incremental outputs until, for example the system microcontroller is ready to receive data.

Figure 6. Incremental Output

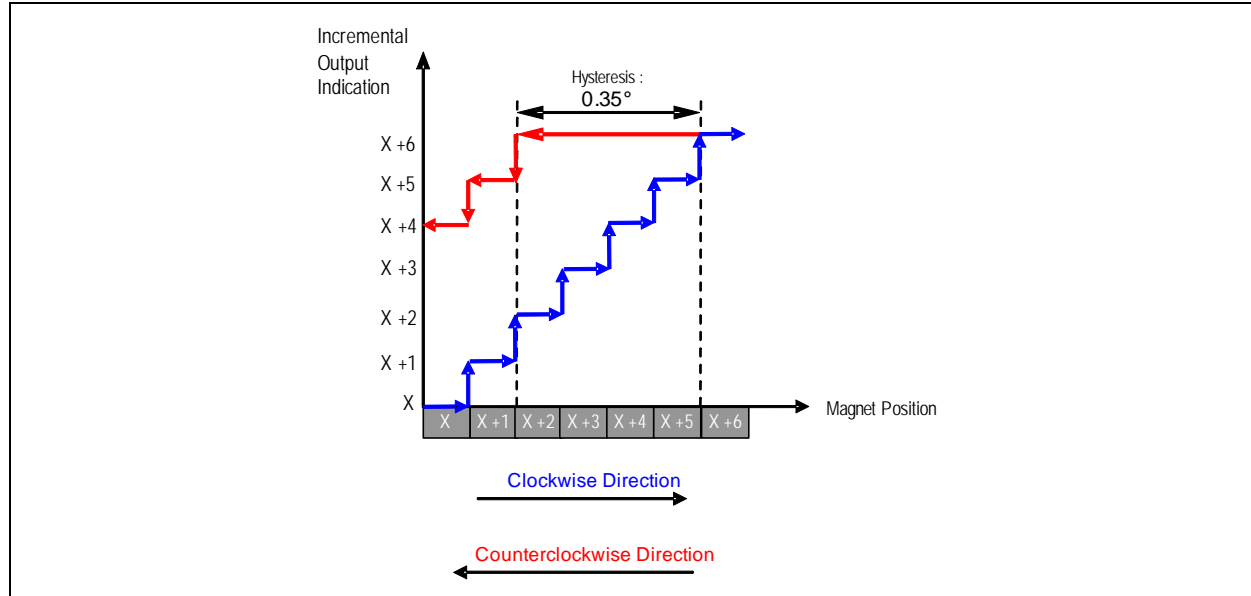


The hysteresis trimming is done at the final test (factory trimming) and set to 4 LSB, related to a 12-bit number.

Incremental Output Hysteresis. To avoid flickering incremental outputs at a stationary magnet position, a hysteresis is introduced. In case of a rotational direction change, the incremental outputs have a hysteresis of 4 LSB. Regardless of the programmed incremental resolution, the hysteresis of 4 LSB always corresponds to the highest resolution of 12-bit. In absolute terms, the hysteresis is set to 0.35 degrees for all resolutions. For constant rotational directions, every magnet position change is indicated at the incremental outputs (see Figure 7). For example, if the magnet turns clockwise from position "x+3" to "x+4", the incremental output would also indicate this position accordingly. A change of the magnet's rotational direction back to position "x+3" means that the incremental output still remains unchanged for the duration of 4 LSB, until position "x+2" is reached. Following this direction, the incremental outputs will again be updated with every change of the magnet position.



Figure 7. Hysteresis Window for Incremental Outputs



Incremental Output Validity. During power on the incremental output is kept stable high until the offset compensation is finished and the CSn is low (internal Pull Up) the first time. In quadrature mode A = B = Index = high indicates an invalid output. If the interpolator recognizes a difference larger than 128 steps between two samples it holds the last valid state. The interpolator synchronizes up again with the next valid difference. This avoids undefined output burst, e.g. if no magnet is present.

8.3 Daisy Chain Mode

The Daisy Chain mode allows connection of several AS5045Bs in series, while still keeping just one digital input for data transfer (see "Data IN" in Figure 8). This mode is accomplished by connecting the data output (DO; pin 9) to the data input (PDIO; pin 8) of the subsequent device. The serial data of all connected devices is read from the DO pin of the first device in the chain. The length of the serial bit stream increases with every connected device, it is $n \cdot (18+1)$ bits: n = number of devices. e.g. 38 bit for two devices, 57 bit for three devices, etc.

The last data bit of the first device (Parity) is followed by a dummy bit and the first data bit of the second device (D11), etc. (see Figure 9).

Figure 8. Daisy Chain Hardware Configuration

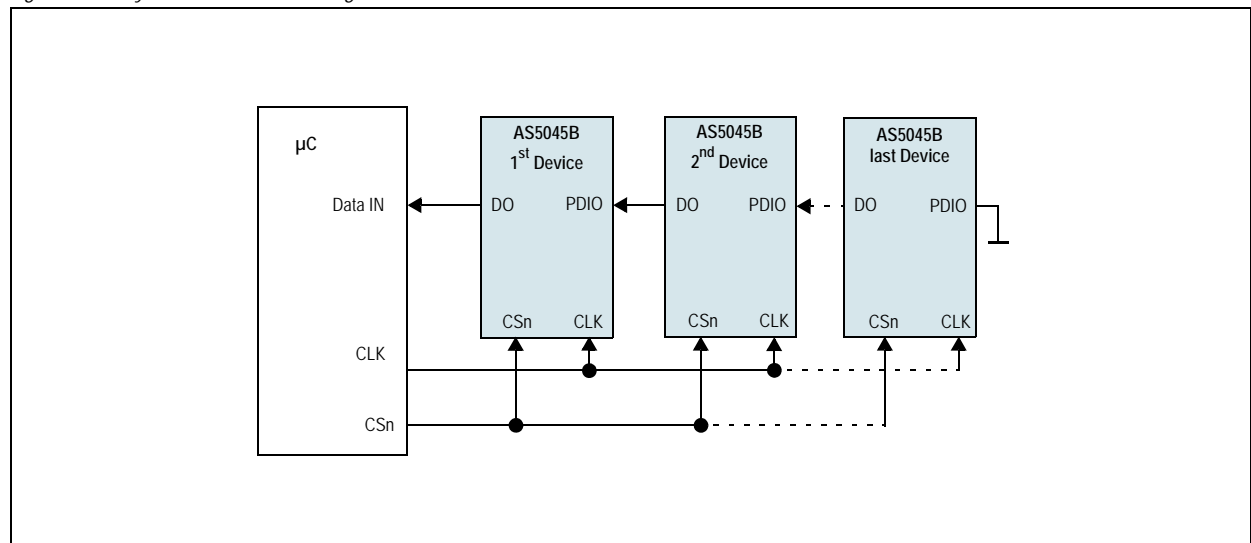
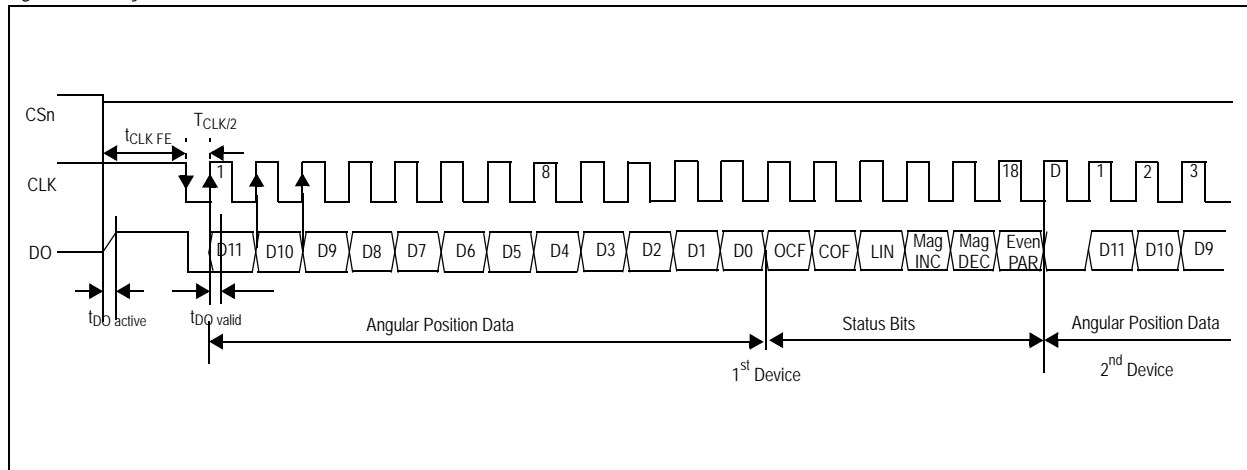




Figure 9. Daisy Chain Mode Data Transfer



8.4 Pulse Width Modulation (PWM) Output

The AS5045B provides a pulse width modulated output (PWM), whose duty cycle is proportional to the measured angle. For angle position 0 to 4094

$$Position = \frac{t_{on} \cdot 4098}{(t_{on} + t_{off})} - 1 \quad (EQ 1)$$

Examples:

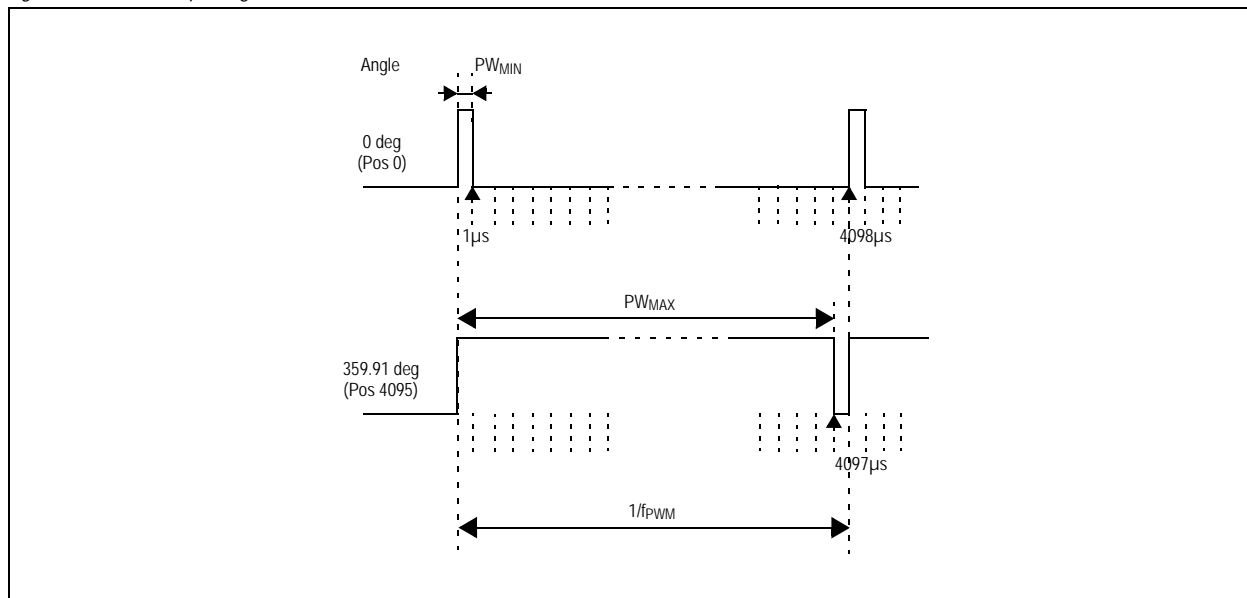
1. An angle position of 180° will generate a pulse width $t_{on} = 2049\mu s$ and a pause t_{off} of $2049\mu s$ resulting in Position = 2048 after the calculation: $2049 \cdot 4098 / (2049 + 2049) - 1 = 2048$
2. An angle position of 359.8° will generate a pulse width $t_{on} = 4095\mu s$ and a pause t_{off} of $3\mu s$ resulting in Position = 4094 after the calculation: $4095 \cdot 4098 / (4095 + 3) - 1 = 4094$

Exception:

1. An angle position of 359.9° will generate a pulse width $t_{on} = 4097\mu s$ and a pause t_{off} of $1\mu s$ resulting in Position = 4096 after the calculation: $4097 \cdot 4098 / (4097 + 1) - 1 = 4096$

The PWM frequency is internally trimmed to an accuracy of $\pm 5\%$ ($\pm 10\%$ over full temperature range). This tolerance can be cancelled by measuring the complete duty cycle as shown above.

Figure 10. PWM Output Signal





8.4.1 Changing the PWM Frequency

The PWM frequency of the AS5045B can be divided by two by setting a bit (PWMhalfEN) in the OTP register (see [Programming the AS5045B on page 17](#)). With PWMhalfEN = 0 the PWM timing is as shown in [Table 9](#):

Table 9. PWM Signal Parameters (Default mode)

Symbol	Parameter	Typ	Unit	Note
f_{PWM}	PWM frequency	244	Hz	Signal period: 4097 μ s
PW_{MIN}	MIN pulse width	1	μ s	- Position 0d - Angle 0 deg
PW_{MAX}	MAX pulse width	4097	μ s	- Position 4095d - Angle 359.91 deg

When PWMhalfEN = 1, the PWM timing is as shown in [Table 10](#):

Table 10. PWM Signal Parameters with Half Frequency (OTP option)

Symbol	Parameter	Typ	Unit	Note
f_{PWM}	PWM frequency	122	Hz	Signal period: 8194 μ s
PW_{MIN}	MIN pulse width	2	μ s	- Position 0d - Angle 0 deg
PW_{MAX}	MAX pulse width	8194	μ s	- Position 4095d - Angle 359.91 deg

8.5 Analog Output

An analog output can be generated by averaging the PWM signal, using an external active or passive low pass filter. The analog output voltage is proportional to the angle: 0° = 0V; 360° = VDD5V.

Using this method, the AS5045B can be used as direct replacement of potentiometers.

Figure 11. Simple 2nd Order Passive RC Low Pass Filter

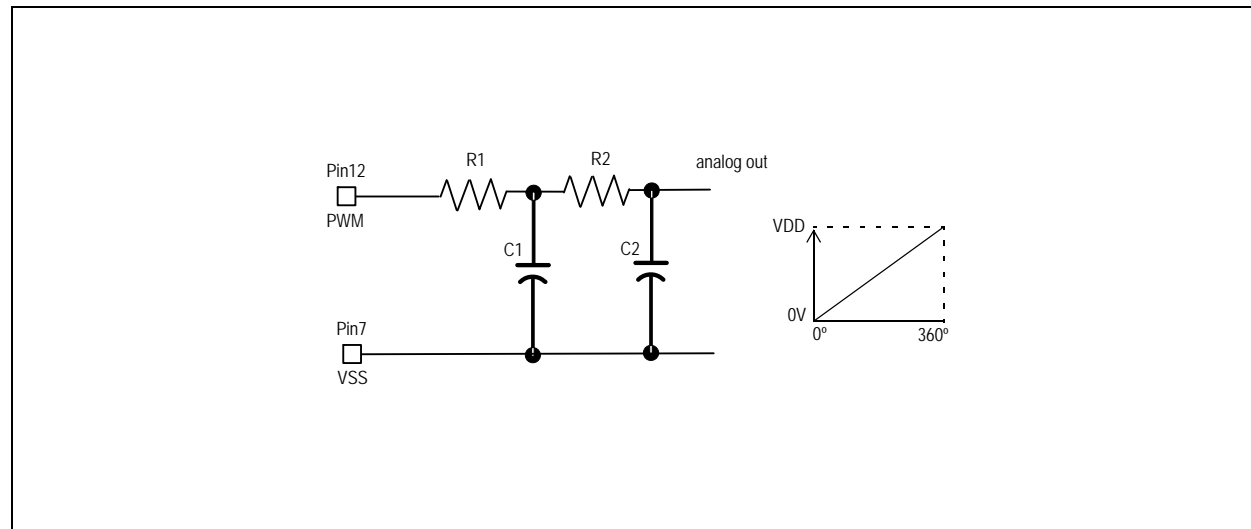


Figure 10 shows an example of a simple passive low pass filter to generate the analog output.

$$R1, R2 \geq 10k\Omega \quad C1, C2 \geq 2.2\mu F / 6V \quad (EQ 2)$$

R1 should be greater than or equal to 4k7 to avoid loading of the PWM output. Larger values of Rx and Cx will provide better filtering and less ripple, but will also slow down the response time.



9 Application Information

The benefits of AS5045B are as follows:

- Complete system-on-chip
- Flexible system solution provides absolute and PWM outputs simultaneously
- Ideal for applications in harsh environments due to contactless position sensing
- No calibration required
- No temperature compensation necessary

9.1 Programming the AS5045B

After power-on, programming the AS5045B is enabled with the rising edge of CSn with PDIO = high and CLK = low.

The AS5045B programming is a one-time-programming (OTP) method, based on poly silicon fuses. The advantage of this method is that a programming voltage of only 3.3V to 3.6V is required for programming (either with 3.3V or 5V supply).

The OTP consists of 52 bits, of which 21 bits are available for user programming. The remaining 31 bits contain factory settings and a unique chip identifier (Chip-ID).

A single OTP cell can be programmed only once. Per default, the cell is "0"; a programmed cell will contain a "1". While it is not possible to reset a programmed bit from "1" to "0", multiple OTP writes are possible, as long as only unprogrammed "0"-bits are programmed to "1".

Independent of the OTP programming, it is possible to overwrite the OTP register temporarily with an OTP write command at any time. This setting will be cleared and overwritten with the hard programmed OTP settings at each power-up sequence or by a LOAD operation. Use **application note AN514X_10** to get more information about the programming options.

The OTP memory can be accessed in the following ways:

- **Load Operation:** The Load operation reads the OTP fuses and loads the contents into the OTP register. A Load operation is automatically executed after each power-on-reset.
- **Write Operation:** The Write operation allows a temporary modification of the OTP register. It does not program the OTP. This operation can be invoked multiple times and will remain set while the chip is supplied with power and while the OTP register is not modified with another Write or Load operation.
- **Read Operation:** The Read operation reads the contents of the OTP register, for example to verify a Write command or to read the OTP memory after a Load command.
- **Program Operation:** The Program operation writes the contents of the OTP register permanently into the OTP ROM.
- **Analog Readback Operation:** The Analog Readback operation allows a quantifiable verification of the programming. For each programmed or unprogrammed bit, there is a representative analog value (in essence, a resistor value) that is read to verify whether a bit has been successfully programmed or not.

9.1.1 Zero Position Programming

Zero position programming is an OTP option that simplifies assembly of a system, as the magnet does not need to be manually adjusted to the mechanical zero position. Once the assembly is completed, the mechanical and electrical zero positions can be matched by software. Any position within a full turn can be defined as the permanent new zero position.

For zero position programming, the magnet is turned to the mechanical zero position (e.g. the "off"-position of a rotary switch) and the actual angular value is read.

This value is written into the OTP register bits Z35:Z46 (see Figure 12).

Note: The zero position value can also be modified before programming, e.g. to program an electrical zero position that is 180° (half turn) from the mechanical zero position, just add 2048 to the value read at the mechanical zero position and program the new value into the OTP register.



9.1.2 OTP Memory Assignment

Table 11. OTP Bit Assignment

Bit	Symbol	Function	
	mbit1	Factory Bit 1	
51	PWMhalfEN_Index width	PMW frequency Index pulse width	Customer Section
50	MagCompEn	Alarm mode (programmed by ams to 1)	
49	pwmDIS	Disable PWM	
48	Reserved	12 bit inc. (programmed by ams) bit 47 to 1, bit 48 to 0	
47	Reserved		
46	Z0	12-bit Zero Position	
:	:		
35	Z11		
34	CCW	Direction	
33	RA0	Redundancy Address	
:	:		
29	RA4		
28	FS 0	Factory Bit	Factory Section
27	FS 1		
26	FS 2		
25	FS 3		
24	FS 4		
23	FS 5		
:	:		
20	FS 8		
19	FS 9		
18	FS 10		
17	ChipID0	18-bit Chip ID	ID Section
16	ChipID1		
:	:		
0	ChipID17		
	mbit0	Factory Bit 0	

9.1.3 User Selectable Settings

The AS5045B allows programming of the following user selectable options:

- **PWMhalfEN_Indexwidth**: Setting this bit, the PWM pulse will be divided by 2, in case of quadrature incremental mode A/B/Index setting of Index impulse width from 1 LSB to 3LSB
- **Z [11:0]**: Programmable Zero / Index Position



- **CCW:** Counter Clockwise Bit
ccw=0 – angular value increases in clockwise direction
ccw=1 – angular value increases in counterclockwise direction
- **RA [4:0]:** Redundant Address: an OTP bit location addressed by this address is always set to "1" independent of the corresponding original OTP bit setting

9.1.4 OTP Default Setting

The AS5045B can also be operated without programming. The default, un-programmed setting is:

- **Z0 to Z11:** 00 = no programmed zero position
- **CCW:** 0 = clockwise operation
- **RA4 to RA0:** 0 = no OTP bit is selected
- **MagCompEN:** 1 = The green/yellow Mode is enabled

9.1.5 Redundancy

For a better programming reliability a redundancy is implemented. In case when the programming of one bit failed this function can be used. With an address RA(4:0) one bit can be selected and programmed.

Table 12. Redundancy Addressing

Address	PWMhalfEN_Indexwidth	MagCompEN	pwmDIS	Reserved	Reserved	Z0	Z1	Z2	Z3	Z4	Z5	Z6	Z7	Z8	Z9	Z10	Z11	CCW
00000	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
00001	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
00010	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
00011	0	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
00100	0	0	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0
00101	0	0	0	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0
00110	0	0	0	0	0	1	0	0	0	0	0	0	0	0	0	0	0	0
00111	0	0	0	0	0	0	1	0	0	0	0	0	0	0	0	0	0	0
01000	0	0	0	0	0	0	0	1	0	0	0	0	0	0	0	0	0	0
01001	0	0	0	0	0	0	0	0	1	0	0	0	0	0	0	0	0	0
01010	0	0	0	0	0	0	0	0	0	1	0	0	0	0	0	0	0	0
01011	0	0	0	0	0	0	0	0	0	0	1	0	0	0	0	0	0	0
01100	0	0	0	0	0	0	0	0	0	0	0	1	0	0	0	0	0	0
01101	0	0	0	0	0	0	0	0	0	0	0	0	1	0	0	0	0	0
01110	0	0	0	0	0	0	0	0	0	0	0	0	0	1	0	0	0	0
01111	0	0	0	0	0	0	0	0	0	0	0	0	0	0	1	0	0	0
10000	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	1	0	0
10001	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	1	0
10010	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	1
10101	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1



9.1.6 Redundant Programming Option

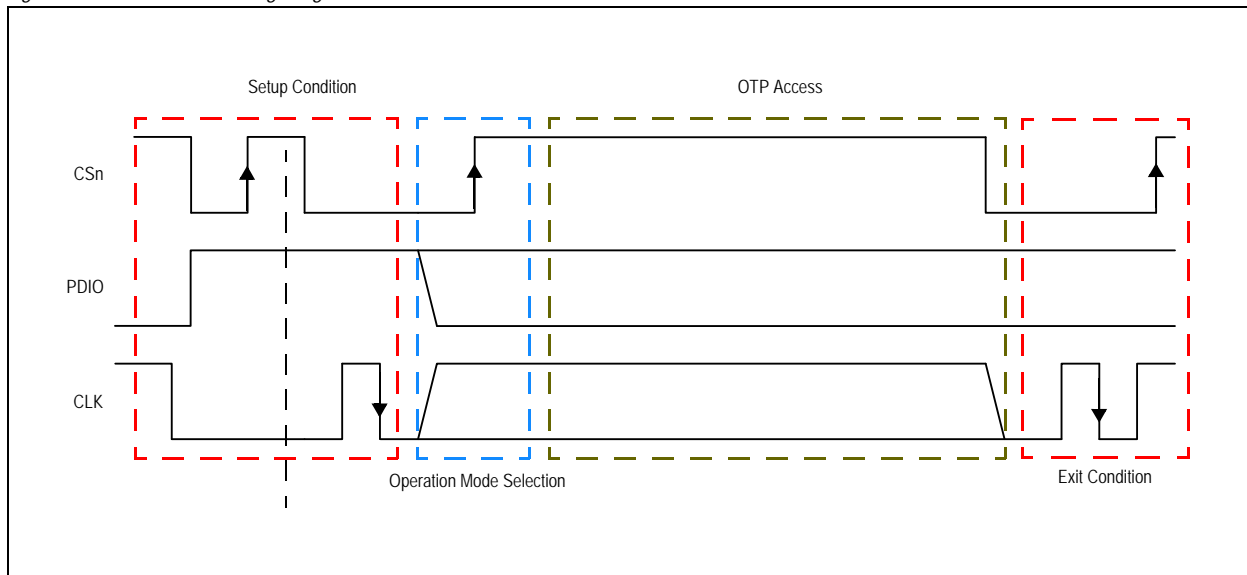
In addition to the regular programming, a redundant programming option is available. This option allows that one selectable OTP bit can be set to "1" (programmed state) by writing the location of that bit into a 5-bit address decoder. This address can be stored in bits RA4...RA0 in the OTP user settings.

Example: setting RA4...0 to "00001" will select bit 51 = PWhalfEN_Indexwidth, "00010" selects bit 50 = MagCompEN, "10010" selects bit 34 = CCW, etc.

9.1.7 OTP Register Entry and Exit Condition

For timing options, refer to [Programming the AS5045B \(page 17\)](#).

Figure 12. OTP Access Timing Diagram



To avoid accidental modification of the OTP during normal operation, each OTP access (Load, Write, Read, Program) requires a defined entry and exit procedure, using the CSn, PDIO and CLK signals as shown in [Figure 12](#).



9.2 Alignment Mode

The alignment mode simplifies centering the magnet over the center of the chip to gain maximum accuracy.

Alignment mode can be enabled with the falling edge of CSn while PDIO = logic high (see Figure 13). The Data bits D11-D0 of the SSI change to a 12-bit displacement amplitude output. A high value indicates large X or Y displacement, but also higher absolute magnetic field strength. The magnet is properly aligned, when the difference between highest and lowest value over one full turn is at a minimum.

Under normal conditions, a properly aligned magnet will result in a reading of less than 128 over a full turn.

The MagINCn and MagDECn indicators will be = 1 when the alignment mode reading is < 128. At the same time, both hardware pins MagINCn (#1) and MagDECn (#2) will be pulled to VSS. A properly aligned magnet will therefore produce a MagINCn = MagDECn = 1 signal throughout a full 360° turn of the magnet.

Stronger magnets or short gaps between magnet and IC will show values larger than 128. These magnets are still properly aligned as long as the difference between highest and lowest value over one full turn is at a minimum.

The Alignment mode can be reset to normal operation by a power-on-reset (disconnect / re-connect power supply) or by a falling edge on CSn with PDIO = low.

Figure 13. Enabling the Alignment Mode

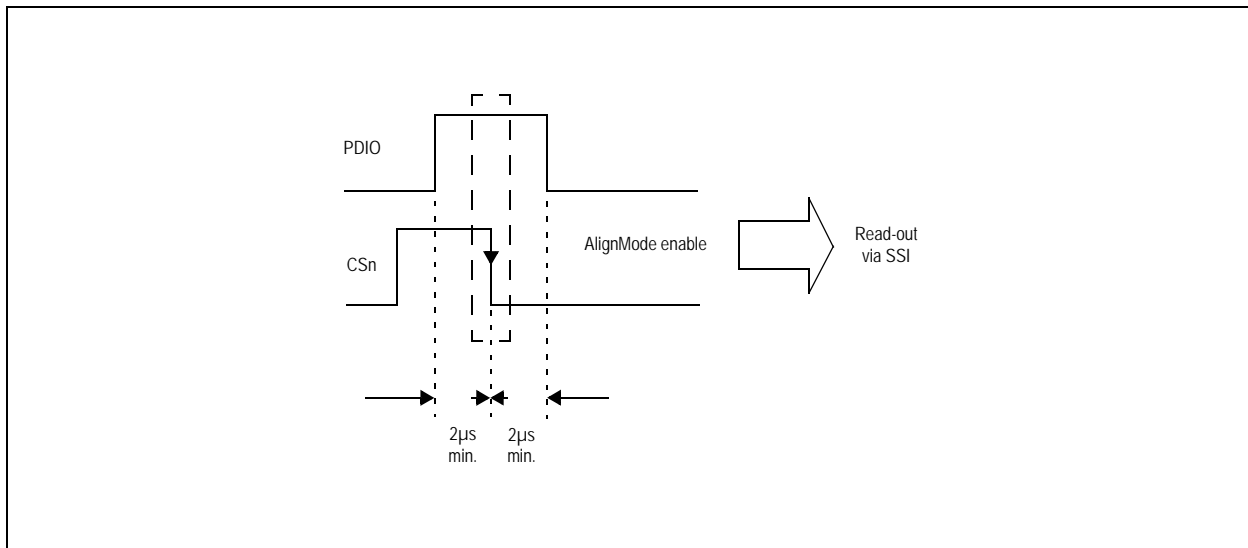
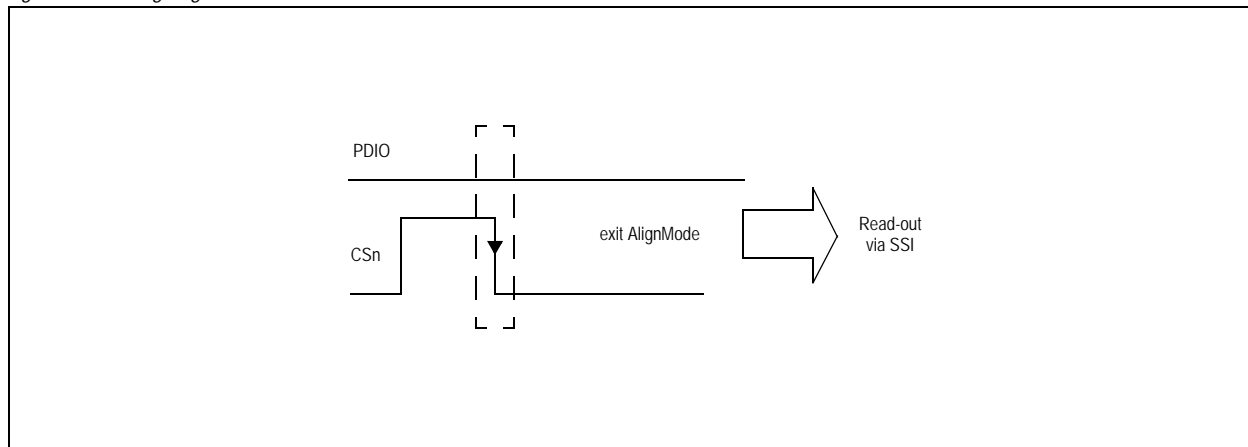


Figure 14. Exiting Alignment Mode





9.3 3.3V / 5V Operation

The AS5045B operates either at 3.3V $\pm 10\%$ or at 5V $\pm 10\%$. This is made possible by an internal 3.3V Low-Dropout (LDO) Voltage regulator. The internal supply voltage is always taken from the output of the LDO, meaning that the internal blocks are always operating at 3.3V.

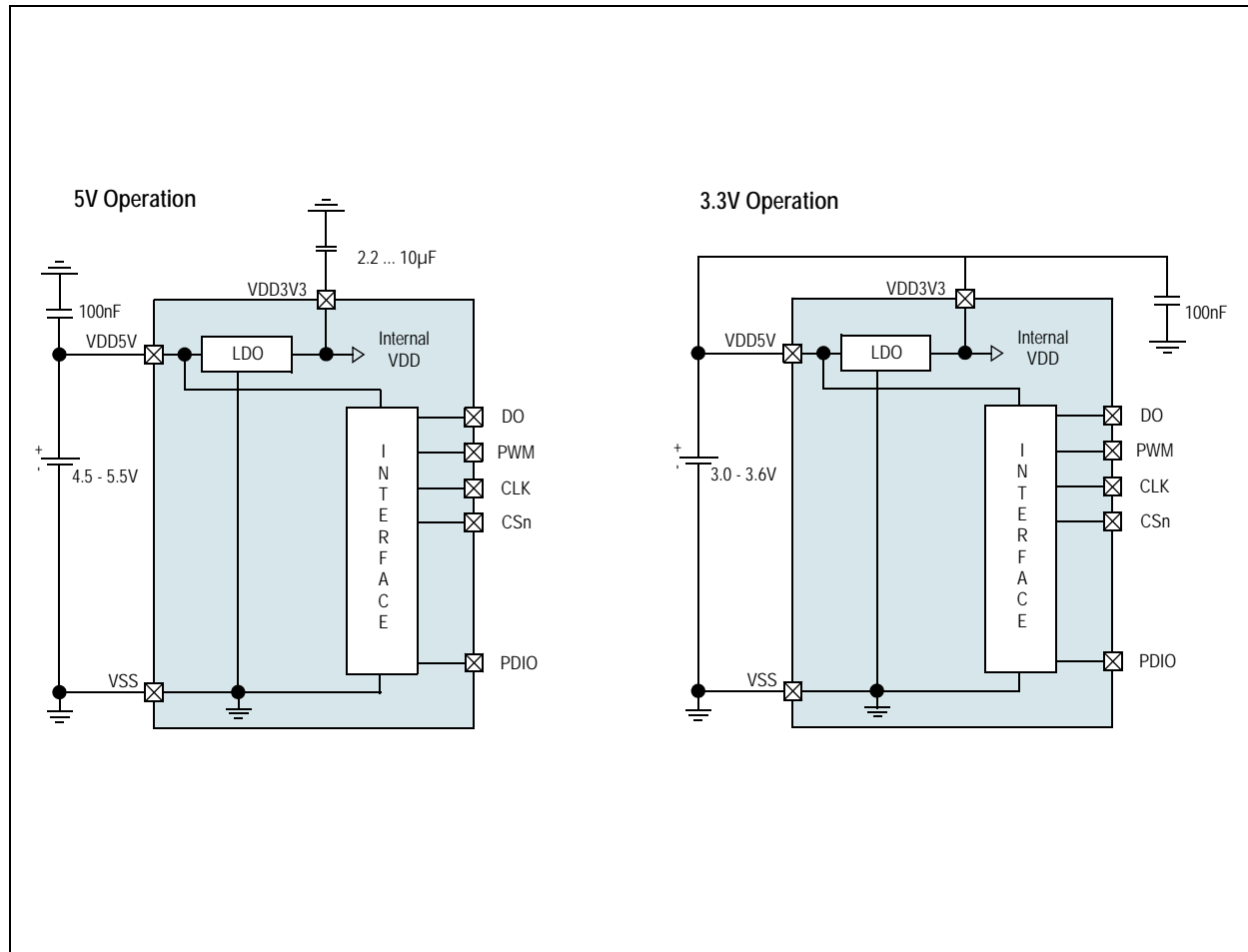
For 3.3V operation, the LDO must be bypassed by connecting VDD3V3 with VDD5V (see Figure 15).

For 5V operation, the 5V supply is connected to pin VDD5V, while VDD3V3 (LDO output) must be buffered by a 1...10 μ F capacitor, which is supposed to be placed close to the supply pin (see Figure 15) with recommended 2.2 μ F).

Note: The VDD3V3 output is intended for internal use only. It must not be loaded with an external load.

The output voltage of the digital interface I/O's corresponds to the voltage at pin VDD5V, as the I/O buffers are supplied from this pin.

Figure 15. Connections for 5V / 3.3V Supply Voltages



A buffer capacitor of 100nF is recommended in both cases close to pin VDD 5V. Note that pin VDD 3V3 must always be buffered by a capacitor. It must not be left floating, as this may cause an instable internal 3.3V supply voltage which can lead to larger than normal jitter of the measured angle.

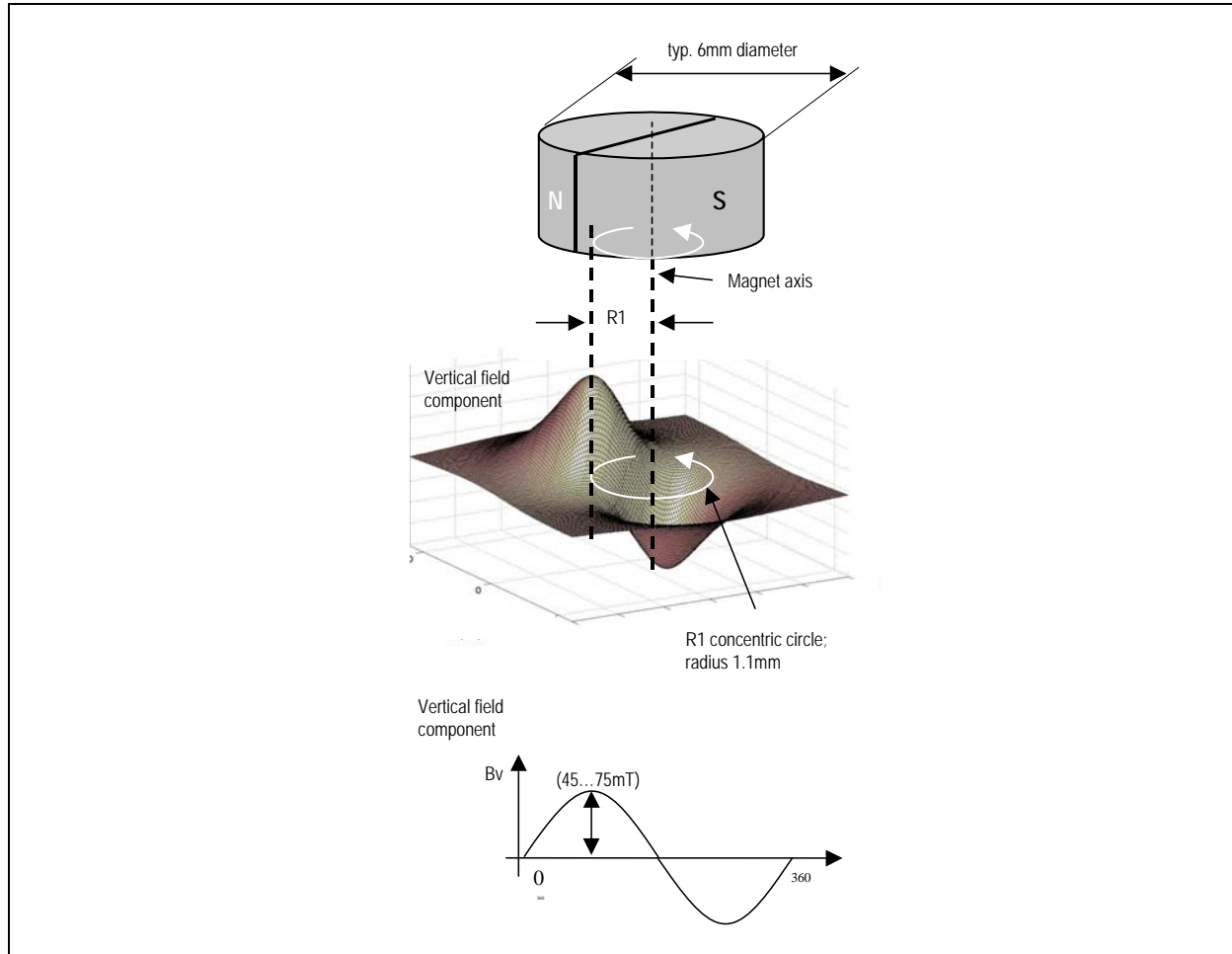
9.4 Selecting Proper Magnet

Typically the magnet is 6mm in diameter and 2.5mm in height. Magnetic materials such as rare earth AlNiCo/SmCo5 or NdFeB are recommended. The magnetic field strength perpendicular to the die surface has to be in the range of $\pm 45\text{mT} \dots \pm 75\text{mT}$ (peak).

The magnet's field strength is verified using a gauss-meter. The magnetic field Bv at a given distance, along a concentric circle with a radius of 1.1mm (R1) is in the range of $\pm 45\text{mT} \dots \pm 75\text{mT}$ (see Figure 16).



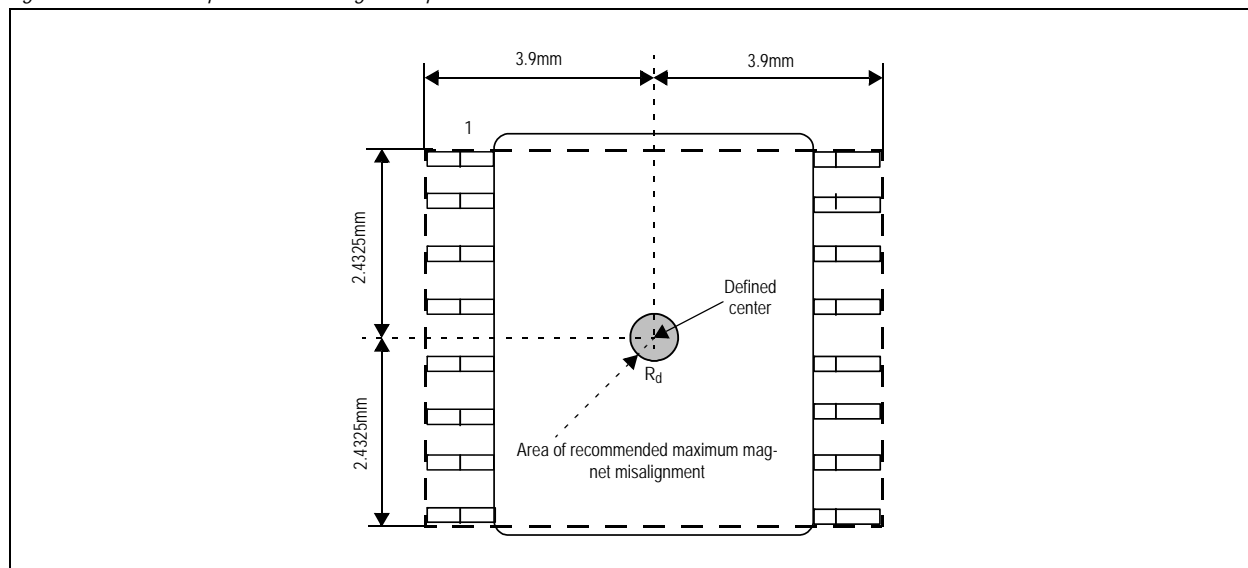
Figure 16. Typical Magnet (6x3mm) and Magnetic Field Distribution



9.4.1 Physical Placement of the Magnet

The best linearity can be achieved by placing the center of the magnet exactly over the defined center of the chip as shown in the drawing below:

Figure 17. Defined Chip Center and Magnet Displacement Radius





9.4.2 Magnet Placement

The magnet's center axis must be aligned within a displacement radius R_d of 0.25mm from the defined center of the IC. The magnet can be placed below or above the device. The distance can be chosen such that the magnetic field on the die surface is within the specified limits (see [Figure 17](#)). The typical distance "z" between the magnet and the package surface is 0.5mm to 1.5mm, provided the use of the recommended magnet material and dimensions (6mm x 3mm). Larger distances are possible, as long as the required magnetic field strength stays within the defined limits.

A magnetic field outside the specified range still can be detected by the chip. But the out-of-range condition will be indicated by MagINCn (pin 1) and MagDECn (pin 2), (see [Table 1](#)).

9.5 Failure Diagnostics

The AS5045B also offers several diagnostic and failure detection features:

9.5.1 Magnetic Field Strength Diagnosis

By software: the MagINC and MagDEC status bits will both be high when the magnetic field is out of range.

By hardware: Pins #1 (MagINCn) and #2 (MagDECn) are open-drain outputs and will both be turned on (= low with external pull-up resistor) when the magnetic field is out of range. If only one of the outputs are low, the magnet is either moving towards the chip (MagINCn) or away from the chip (MagDECn).

9.5.2 Power Supply Failure Detection

By software: If the power supply to the AS5045B is interrupted, the digital data read by the SSI will be all "0"s. Data is only valid, when bit OCF is high, hence a data stream with all "0"s is invalid. To ensure adequate low levels in the failure case, a pull-down resistor ($\sim 10k\Omega$) must be added between pin DIO and VSS at the receiving side.

By hardware: The MagINCn and MagDECn pins are open drain outputs and require external pull-up resistors. In normal operation, these pins are high ohmic and the outputs are high (see [Table 8](#)). In a failure case, either when the magnetic field is out of range of the power supply is missing, these outputs will become low. To ensure adequate low levels in case of a broken power supply to the AS5045B, the pull-up resistors ($\sim 10k\Omega$) from each pin must be connected to the positive supply at pin 16 (VDD5V).

By hardware: PWM output: The PWM output is a constant stream of pulses with 1kHz repetition frequency. In case of power loss, these pulses are missing.

9.6 Angular Output Tolerances

9.6.1 Accuracy

Accuracy is defined as the error between measured angle and actual angle. It is influenced by several factors:

- The non-linearity of the analog-digital converters
- Internal gain and mismatch errors
- Non-linearity due to misalignment of the magnet

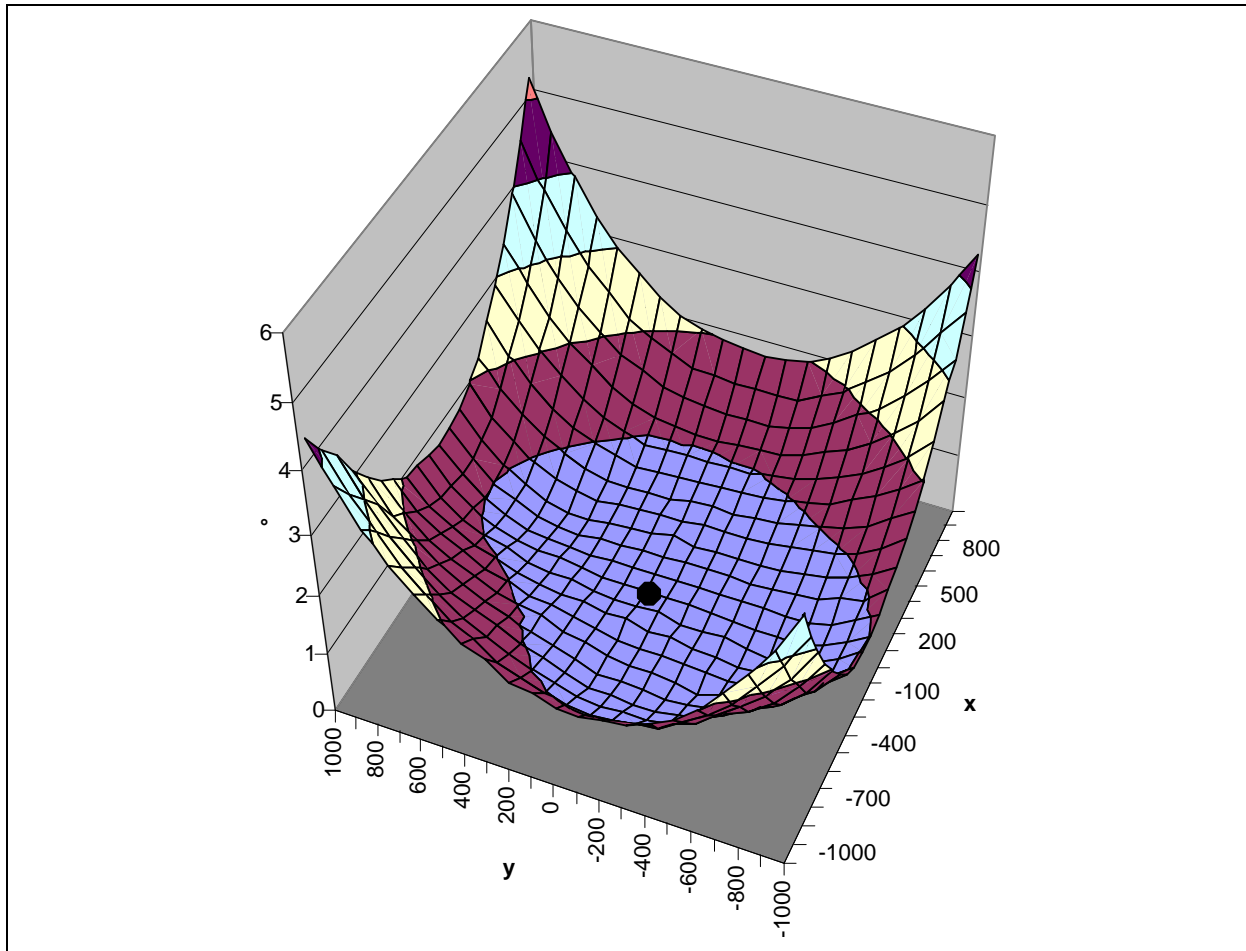
As a sum of all these errors, the accuracy with centered magnet = $(Err_{max} - Err_{min})/2$ is specified as better than ± 0.5 degrees @ 25°C (see [Figure 19](#)).

Misalignment of the magnet further reduces the accuracy. [Figure 18](#) shows an example of a 3D-graph displaying non-linearity over XY-misalignment. The center of the square XY-area corresponds to a centered magnet (see dot in the center of the graph). The X- and Y- axis extends to a misalignment of ± 1 mm in both directions. The total misalignment area of the graph covers a square of 2x2mm (79x79mil) with a step size of 100 μ m.

For each misalignment step, the measurement as shown in [Figure 19](#) is repeated and the accuracy $(Err_{max} - Err_{min})/2$ (e.g. 0.25° in [Figure 19](#)) is entered as the Z-axis in the 3D-graph.



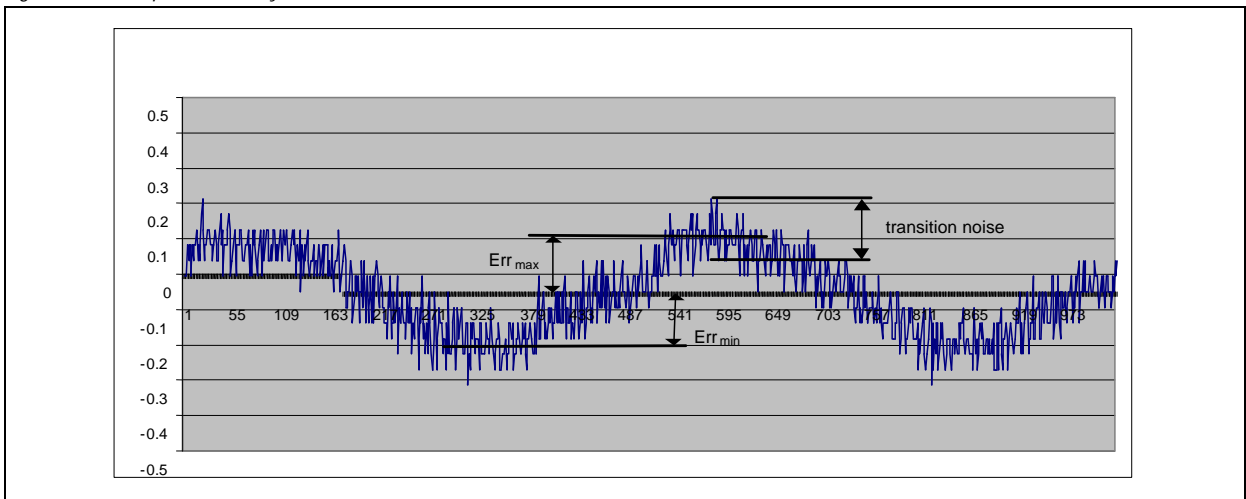
Figure 18. Example of Linearity Error Over XY Misalignment



The maximum non-linearity error on this example is better than ± 1 degree (inner circle) over a misalignment radius of ~ 0.7 mm. For volume production, the placement tolerance of the IC within the package (± 0.235 mm) must also be taken into account.

The total nonlinearity error over process tolerances, temperature and a misalignment circle radius of 0.25mm is specified better than ± 1.4 degrees. The magnet used for this measurement was a cylindrical NdFeB (Bomatec® BMN-35H) magnet with 6mm diameter and 2.5mm in height.

Figure 19. Example of Linearity Error Over 360°





9.6.2 Transition Noise

Transition noise is defined as the jitter in the transition between two steps. Due to the nature of the measurement principle (Hall sensors + Preamplifier + ADC), there is always a certain degree of noise involved. This transition noise voltage results in an angular transition noise at the outputs. It is specified as 0.06 degrees rms (1 sigma)x1.

This is the repeatability of an indicated angle at a given mechanical position. The transition noise has different implications on the type of output that is used:

- **PWM interface:** If the PWM interface is used as an analog output by adding a low pass filter, the transition noise can be reduced by lowering the cutoff frequency of the filter. If the PWM interface is used as a digital interface with a counter at the receiving side, the transition noise can be further reduced by averaging of readings.
- **Incremental mode:** In incremental mode, the transition noise influences the period, width and phase shift of the output signals A, B and Index. However, the algorithm used to generate the incremental outputs guarantees no missing or additional pulses even at high speeds (up to 15,000 rpm and higher).

Note: Statistically, 1 sigma represents 68.27% of readings and 3 sigma represents 99.73% of readings.

9.6.3 High Speed Operation

- **Sampling Rate:** The AS5045B samples the angular value at a rate of 10.42k samples per second. Consequently, the absolute outputs are updated each 96µs. At a stationary position of the magnet, the sampling rate creates no additional error.
- **Absolute Mode:** At a sampling rate of 10.4kHz, the number of samples (n) per turn for a magnet rotating at high speed can be calculated by

$$n = \frac{60}{rpm \cdot 96\mu s} \quad (EQ 3)$$

The upper speed limit is ~30,000 rpm. The only restriction at high speed is that there will be fewer samples per revolution as the speed increases (see Table 7). Regardless of the rotational speed, the absolute angular value is always sampled at the highest resolution of 12-bit.

- **Incremental Mode:** Incremental encoders are usually required to produce no missing pulses up to several thousand rpm. Therefore, the AS5045B has a built-in interpolator, which ensures that there are no missing pulses at the incremental outputs for rotational speeds of up to 15,000 rpm, even at the highest resolution of 12 bits (4096 pulses per revolution).

9.6.4 Propagation Delays

The propagation delay is the delay between the time that the sample is taken until it is converted and available as angular data. This delay is 96µs.

Using the SSI interface for absolute data transmission, an additional delay must be considered, caused by the asynchronous sampling (0 ... 1/fsample) and the time it takes the external control unit to read and process the angular data from the chip (maximum clock rate = 1MHz, number of bits per reading = 18).

Angular Error Caused by Propagation Delay: A rotating magnet will cause an angular error caused by the output propagation delay. This error increases linearly with speed:

$$e_{sampling} = rpm * 6 * prop.delay \quad (EQ 4)$$

Where:

esampling = angular error [°]
rpm = rotating speed [rpm]
prop.delay = propagation delay [seconds]

Note: Since the propagation delay is known, it can be automatically compensated by the control unit processing the data from the AS5045B.

9.6.5 Internal Timing Tolerance

The AS5045B does not require an external ceramic resonator or quartz. All internal clock timings for the AS5045B are generated by an on-chip RC oscillator. This oscillator is factory trimmed to ±5% accuracy at room temperature (±10% over full temperature range). This tolerance influences the ADC sampling rate and the pulse width of the PWM output:

- Absolute output; SSI interface: A new angular value is updated every 96µs (typ).
- PWM output: A new angular value is updated every 96µs (typ). The PWM pulse timings T_{on} and T_{off} also have the same tolerance as the internal oscillator. If only the PWM pulse width T_{on} is used to measure the angle, the resulting value also has this timing tolerance. However, this tolerance can be cancelled by measuring both T_{on} and T_{off} and calculating the angle from the duty cycle (see Pulse Width Mod).



[ulation \(PWM\) Output on page 15\)](#)

9.6.6 Temperature

Magnetic Temperature Coefficient. One of the major benefits of the AS5045B compared to linear Hall sensors is that it is much less sensitive to temperature. While linear Hall sensors require a compensation of the magnet's temperature coefficients, the AS5045B automatically compensates for the varying magnetic field strength over temperature. The magnet's temperature drift does not need to be considered, as the AS5045B operates with magnetic field strengths from $\pm 45 \dots \pm 75 \text{mT}$.

Example: A NdFeB magnet has a field strength of 75mT @ -40°C and a temperature coefficient of -0.12% per Kelvin. The temperature change is from -40° to $+125^\circ = 165\text{K}$. The magnetic field change is: $165 \times -0.12\% = -19.8\%$, which corresponds to 75mT at -40°C and 60mT at 125°C .

The AS5045B can compensate for this temperature related field strength change automatically, no user adjustment is required.

9.6.7 Accuracy over Temperature

The influence of temperature in the absolute accuracy is very low. While the accuracy is less than or equal to $\pm 0.5^\circ$ at room temperature, it can increase to less than or equal to $\pm 0.9^\circ$ due to increasing noise at high temperatures.

Timing Tolerance over Temperature. The internal RC oscillator is factory trimmed to $\pm 5\%$. Over temperature, this tolerance can increase to $\pm 10\%$. Generally, the timing tolerance has no influence in the accuracy or resolution of the system, as it is used mainly for internal clock generation.

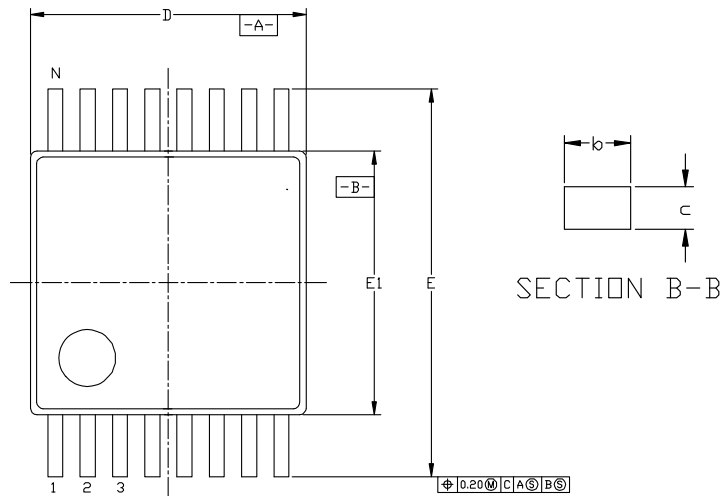
The only concern to the user is the width of the PWM output pulse, which relates directly to the timing tolerance of the internal oscillator. This influence however can be cancelled by measuring the complete PWM duty cycle instead of just the PWM pulse.



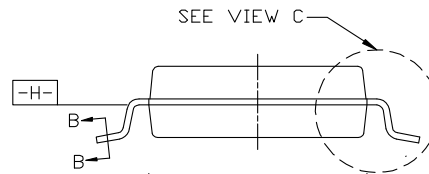
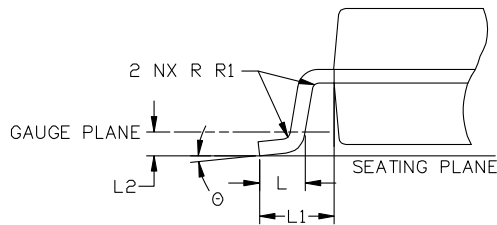
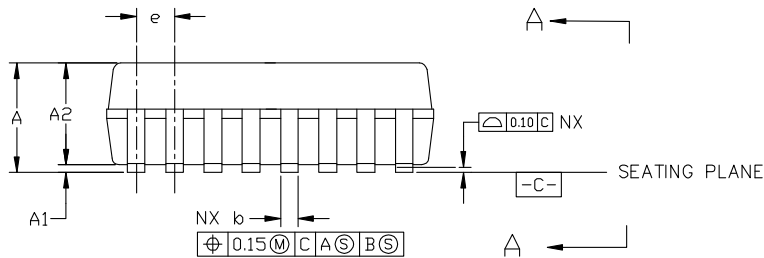
10 Package Drawings and Markings

The device is available in SSOP 16 (5.3mm x 6.2mm).

Figure 20. Package Drawings and Dimensions



Symbol	Min	Nom	Max
A	1.73	1.86	1.99
A1	0.05	0.13	0.21
A2	1.68	1.73	1.78
b	0.22	0.315	0.38
c	0.09	0.17	0.25
D	5.90	6.20	6.50
E	7.40	7.80	8.20
E1	5.00	5.30	5.60
e	-	0.65 BSC	-
L	0.55	0.75	0.95
L1	-	1.25 REF	-
L2	-	0.25 BSC	-
R	0.09	-	-
Θ	0°	4°	8°
N	16		



Notes:

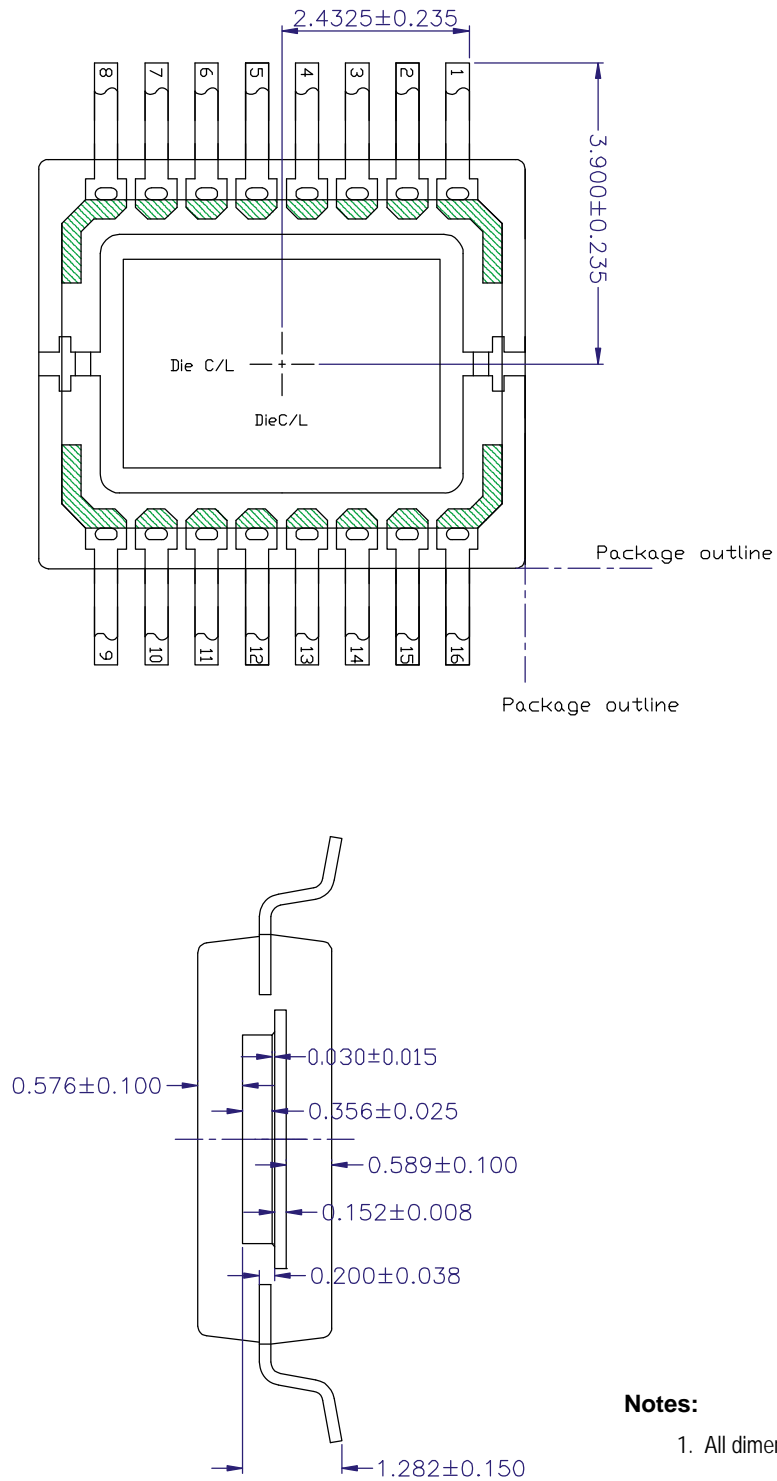
1. Dimensions and tolerancing conform to ASME Y14.5M-1994.
2. All dimensions are in millimeters. Angles are in degrees.

Marking: YYWWMZZ.

YY	WW	M	ZZ
Last two digits of the manufacturing year	Manufacturing week	Plant identifier	Assembly traceability code



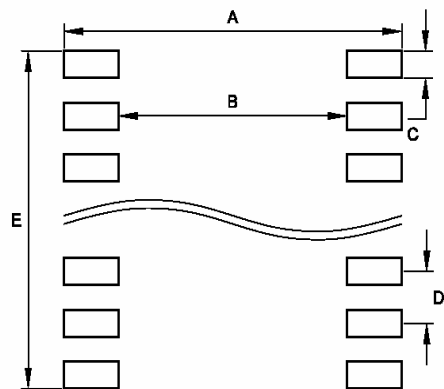
Figure 21. Vertical Cross Section of SSOP-16





10.1 Recommended PCB Footprint

Figure 22. PCB Footprint



Recommended Footprint Data	
Symbol	mm
A	9.02
B	6.16
C	0.46
D	0.65
E	5.01



Revision History

Revision	Date	Owner	Description
1.0	03 July, 2013	mub	Initial Revision



11 Ordering Information

The devices are available as the standard products shown in [Table 13](#).

Table 13. Ordering Information

Ordering Code	Description	Delivery Form	Package
AS5045B-ASST	Pre-programmed 12-bit incremental (125 °C)	Tape&Reel (13")	SSOP 16 (5.3mm x 6.2mm)
AS5045B-ASSM	Pre-programmed 12-bit incremental (125 °C)	Tape&Reel (7")	

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